

## MBS Plastic-Encapsulate Bridge Rectifier

### MB05S THRU MB10S General Purpose Bridge Rectifier

#### Features

- $I_{F(AV)}$  1A
- $V_{RRM}$  50V-1000V
- High surge current capability
- Glass passivated chip

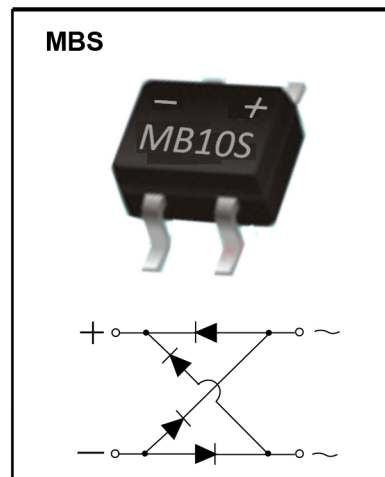
#### Applications

- General purpose 1 phase Bridge rectifier applications

#### Marking

- MBXXS

X : From 05 To 10



#### Limiting Values (Absolute Maximum Rating)

| Item   | Symbol         | Unit        | Conditions   | MB         |     |     |     |     |     |      |
|--|----------------|-------------|--|------------|-----|-----|-----|-----|-----|------|
|  |                |             |  | 05S        | 1S  | 2S  | 4S  | 6S  | 8S  | 10S  |
| Repetitive Peak Reverse Voltage                  | $V_{RRM}$      | V           |  | 50         | 100 | 200 | 400 | 600 | 800 | 1000 |
| Maximum RMS Voltage                              | $V_{RMS}$      | V           |  | 35         | 70  | 140 | 280 | 420 | 560 | 700  |
| Average Rectified Output Current                 | $I_O$          | A           | 60Hz sine wave, R-load, $T_a=40^{\circ}C$                    | 1.0        |     |     |     |     |     |      |
| Surge(Non-repetitive) Forward Current            | $I_{FSM}$      | A           | 60Hz half sine wave, 1 cycle, $T_j=25^{\circ}C$              | 35         |     |     |     |     |     |      |
| Current Squared Time                             | $I^2t$         | $A^2S$      | $1ms \leq t < 8.3ms$ $T_j=25^{\circ}C$ , Rating of per diode | 5.83       |     |     |     |     |     |      |
| Operation Junction and Storage Temperature Range | $T_J, T_{stg}$ | $^{\circ}C$ |  | -55 ~ +150 |     |     |     |     |     |      |

#### Electrical Characteristics ( $T_a=25^{\circ}C$ Unless otherwise specified)

| Item                 | Symbol           | Unit          | Test Condition  | Max |
|----------------------|------------------|---------------|---|-----|
| Peak Forward Voltage | $V_{FM}$         | V             | $I_{FM}=1.0A$ , Pulse measurement, Rating of per diode    | 1.0 |
| Peak Reverse Current | $I_{RRM}$        | $\mu A$       | $V_{RM}=V_{RRM}$ , Pulse measurement, Rating of per diode | 10  |
| Thermal Resistance   | $R_{\theta J-A}$ | $^{\circ}C/W$ | Between junction and ambient, On alumina substrate        | 76  |
|                      |                  |               | Between junction and ambient, On glass-epoxi substrate    | 134 |
|                      | $R_{\theta J-L}$ |               | Between junction and lead                                 | 20  |

## Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

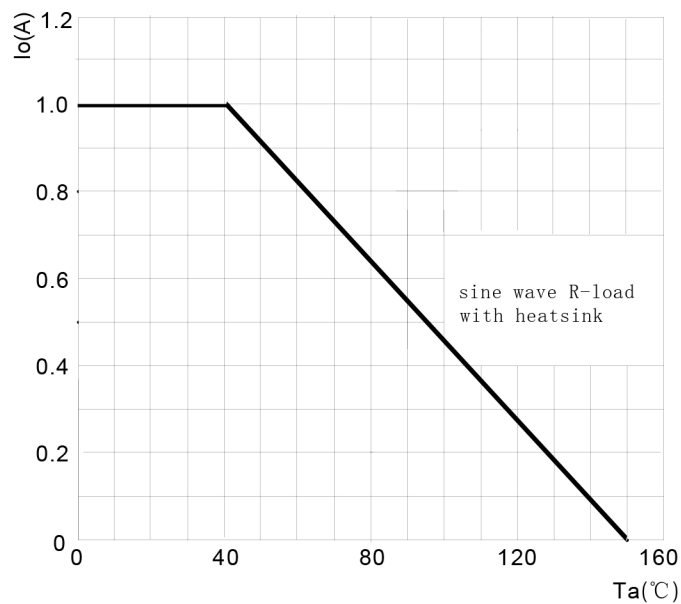


FIG.2: MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

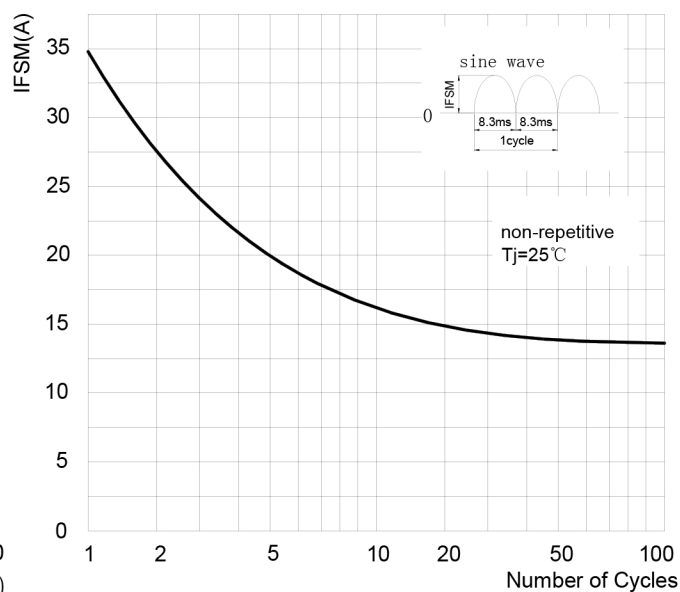


FIG.3: TYPICAL FORWARD CHARACTERISTICS

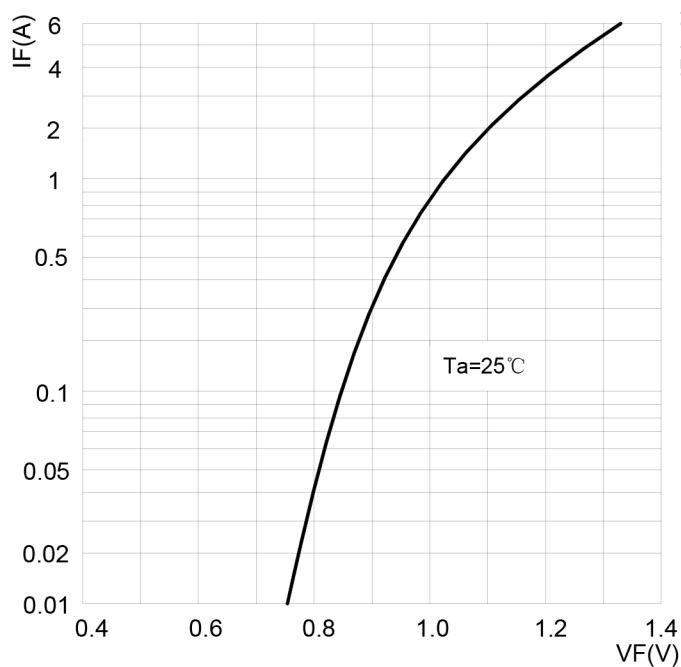
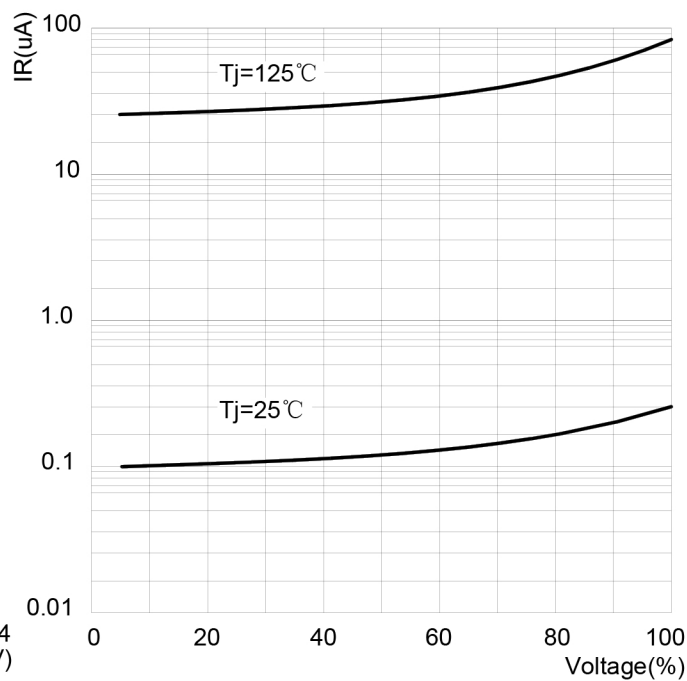


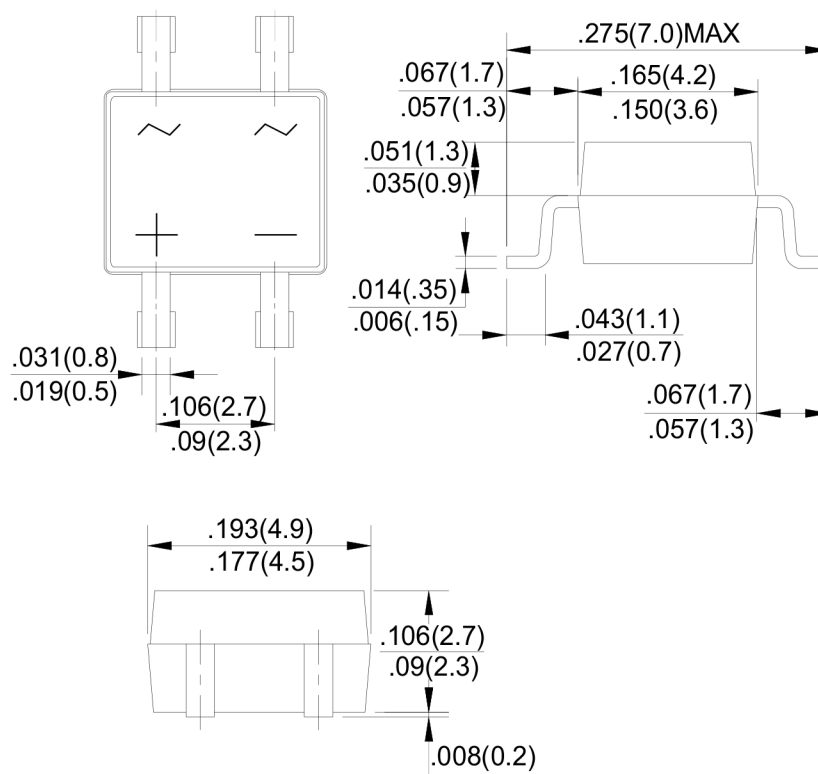
FIG.4: TYPICAL REVERSE CHARACTERISTICS



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## MBS Package Outline Dimensions

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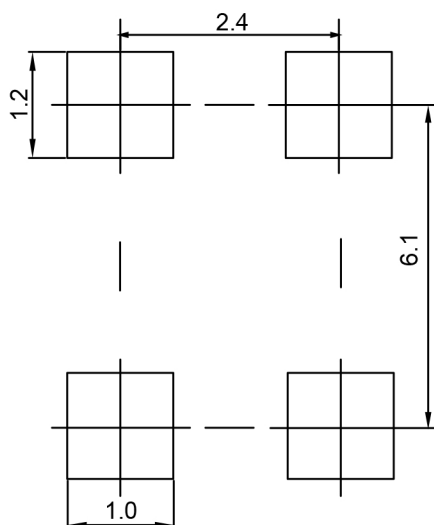


Dimensions in inches and (millimeters)

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## MBS Suggested Pad Layout

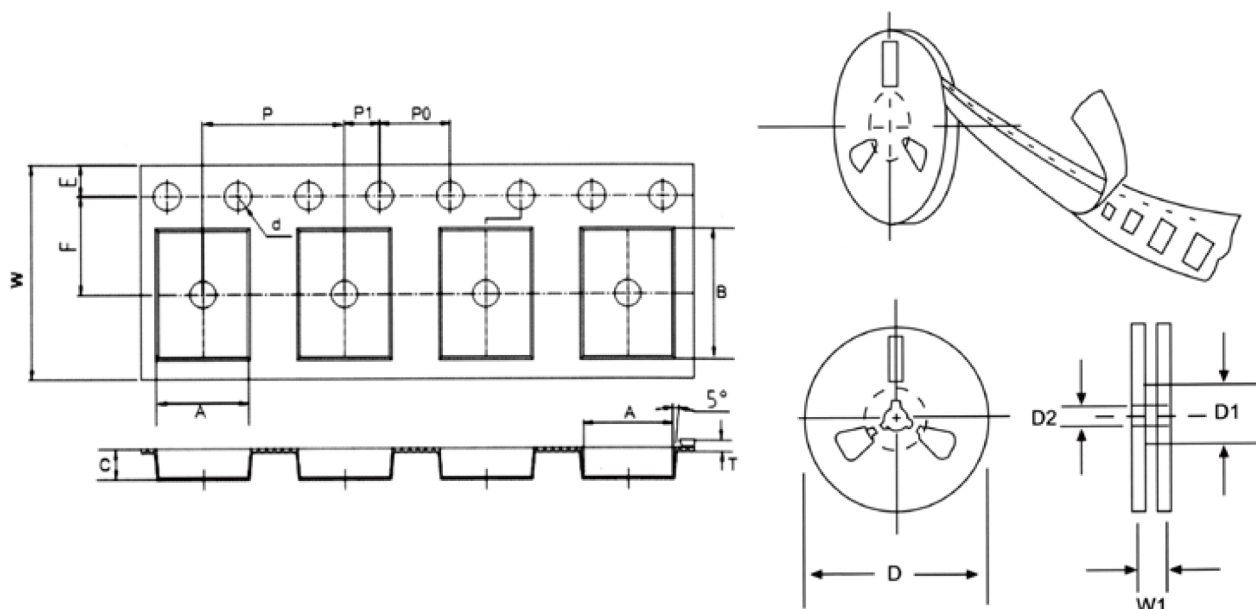
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**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

## Reel Taping Specifications For Surface Mount Devices-MBS



**FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING**

| ITEM                  | SYMBOL | MBS mm(inch)               |
|-----------------------|--------|----------------------------|
| Carrier width         | A      | 5.05+0.1(0.198+0.004)      |
| Carrier length        | B      | 7.22+0.1(0.284+0.004)      |
| Carrier depth         | C      | 2.88+0.1(0.113+0.004)      |
| Sprocket hole         | d      | 1.55±0.05 (0.061±0.002)    |
| Reel outside diameter | D      | 330±2.0(13±0.079)          |
| Reel inner diameter   | D1     | 75 ±1.0 ( 2.95 ±0.039)     |
| Feed hole diameter    | D2     | 13+0.5(0.512+0.020)        |
| Stroket hole position | E      | 1.75+0.1(0.069+0.004)      |
| Punch hole position   | F      | 5.50+0.05(0.217+0.002)     |
| Punch hole pitch      | P      | 8.0+0.1(0.315+0.004)       |
| Sprocket hole pitch   | P0     | 4.0+0.1(0.157+0.004)       |
| Embossment center     | P1     | 2.0+0.1(0.079+0.004)       |
| Totall tape thickness | T      | 0.20-0.70(0.080-0.028)     |
| Tape width            | W      | 12.0+0.3/-0.1(0.472+0.004) |
| Reel width            | W1     | 16.8+2.0(0.661+0.079)      |

NOTE: Devices are packde in accordance with EIA standard RS-481-A and specification given above.